

Chip Card Interface Device

STD200

<p>Feature:</p> <ul style="list-style-type: none">● Both USB and UART Interface<ul style="list-style-type: none">➤ Full speed bulk, control and interrupt transfer types compliant with USB specification➤ USB Suspend/Resume operations➤ On-Chip 3.3V USB voltage regulator➤ Software emulated UART● Smartcard interface specification compliant with ISO7816, GSM, EMV, and PC/SC (WHQL)● Communication protocols compliant with CCID specification● Built-in Step-up/down Converter<ul style="list-style-type: none">➤ Automatic recognize and access 5V/3V/1.8V (Class A, B, C) Smartcard➤ Current overload protection● Built-in ISO7816 UART<ul style="list-style-type: none">➤ Direct Connection to Smartcard Terminals➤ Automatic retry on parity error➤ Automatic character repetition on parity error➤ Card Clock Stop High or Low for Card Power-down Mode➤ Card Detection and Automatic De-activation Sequence➤ 4 KV ESD protection for all Smartcard Interface I/Os	<ul style="list-style-type: none">● Multi-protocols with smartcard:<ul style="list-style-type: none">➤ Access ISO 7816 asynchronous Smartcard T=0 /T=1 protocols➤ PTS management➤ Direct/Inverse conversion➤ Wide range communication baud rate up to 11.625 clock pulses (D=32/F=372)➤ IFSD adjustable➤ Full function of S-block: WTX, Abort, IFS● LED indication● Package: 24 pin SO <p>Application:</p> <ul style="list-style-type: none">● Security & Identification<ul style="list-style-type: none">➤ Smart card reader➤ Fingerprint Identifier● Access control & E-Commerce<ul style="list-style-type: none">➤ PC/ Notebook PC & PDA● Banking & Payment system<ul style="list-style-type: none">➤ ATM & EFT POS terminal➤ KIOSK & Vending machine● Telecommunication & I.A<ul style="list-style-type: none">➤ Set-top box &, Thin-Client➤ Pay-phone
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The STD200 was developed to provide the designer with a single chip and low cost solution for smart card reader device offering a simple and easy way to connect to the smart cards. By using the STD200, the designer eliminates the task of assuring ISO 7816, GSM, EMV, PC/SC, and CCID specification compliance and the necessity of understanding smart card timing requirements when interfacing a smart card application.

Figure 1. STD200 Block Diagram

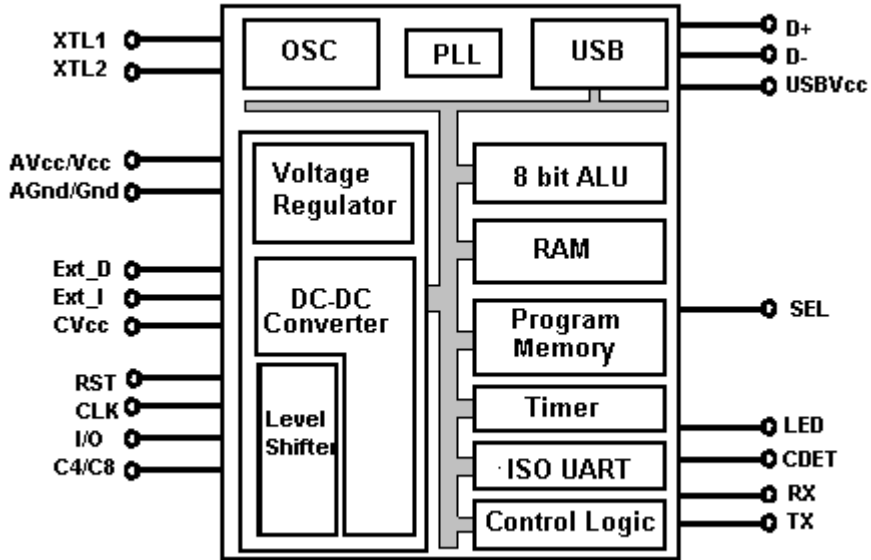


Figure 2. Reference Application: USB Interface Smartcard Reader

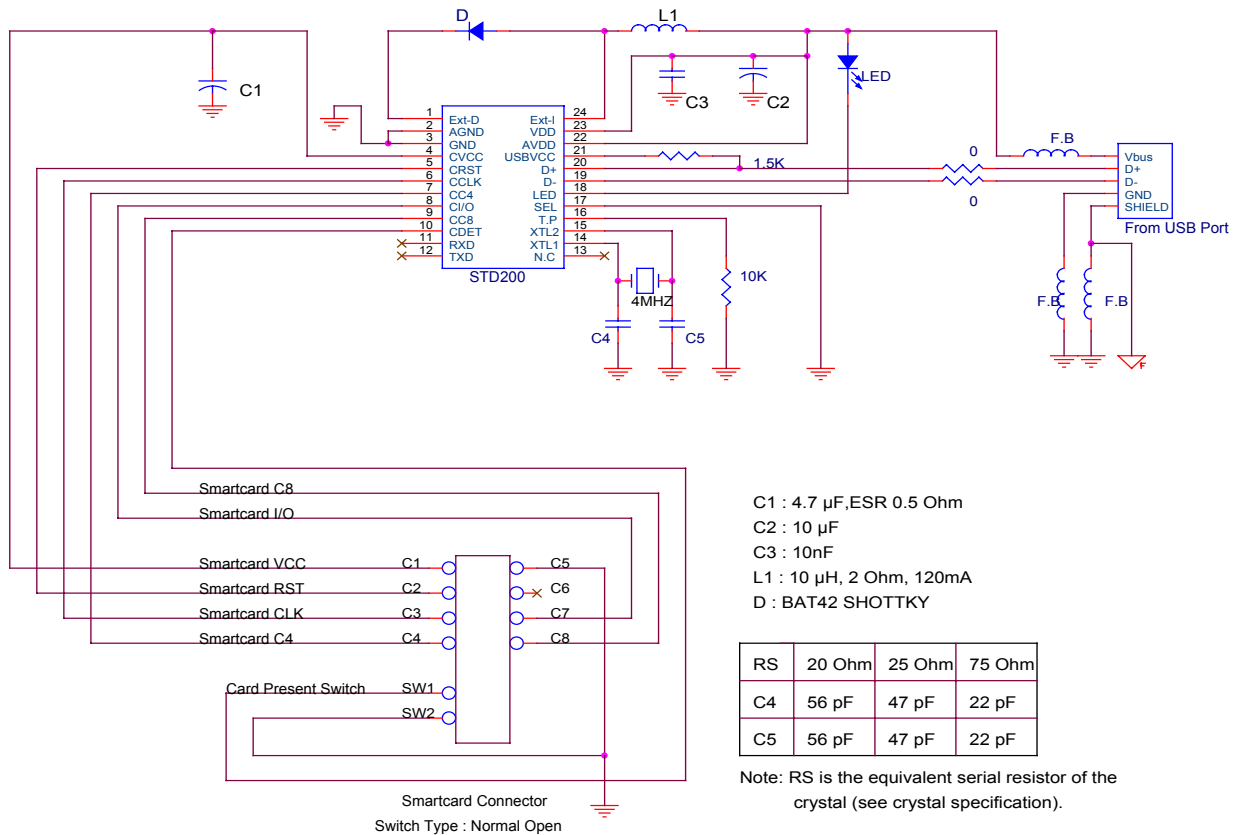
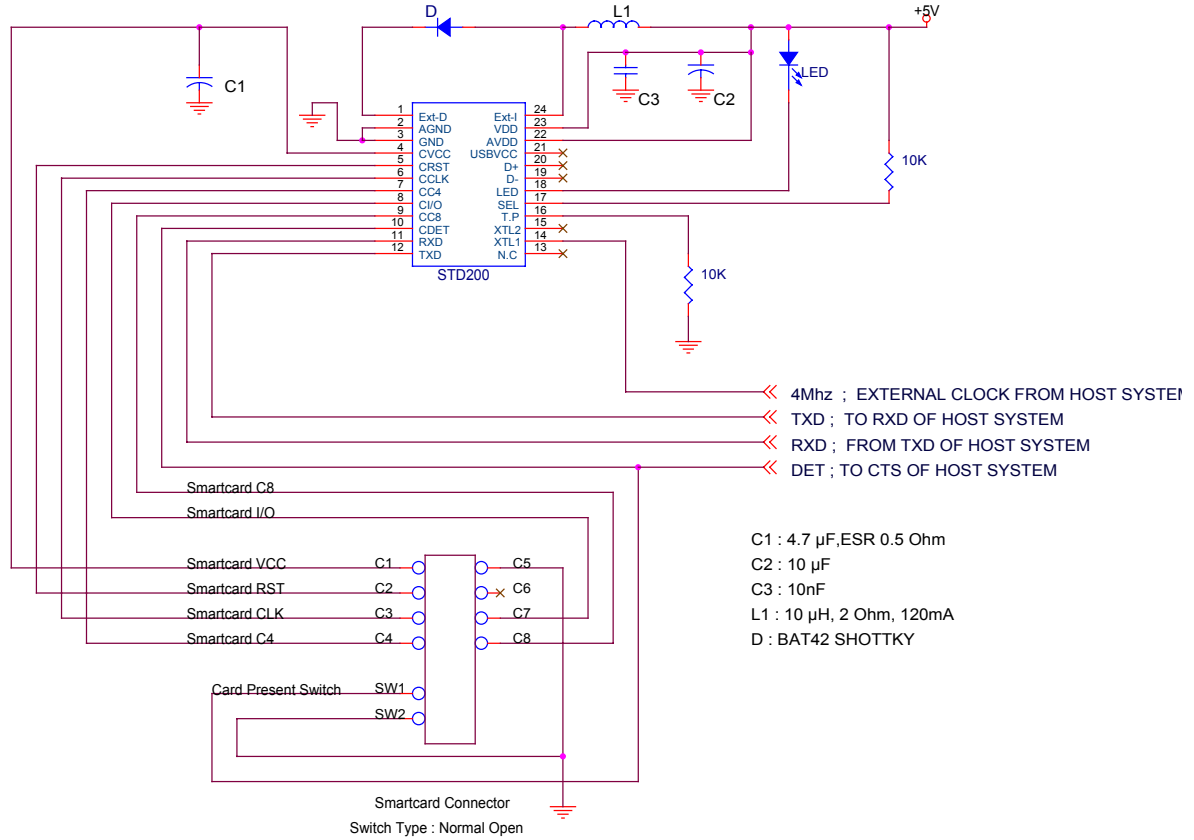
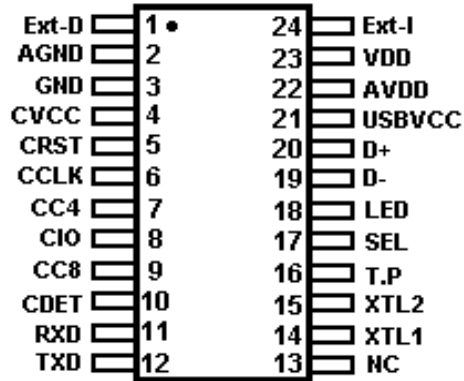


Figure 3. Reference Application: UART Interface Smartcard Reader



STD200 Pin Description

Figure 4 STD200 Pinout



STD200 Pin Description			
Pin No	Signal	Type	Descriptions
23	VDD	P	Supply voltage.
22	AVDD	P	Analog power supply.
21	USB VCC	P	3.3V output for USB.
3	GND	P	Circuit ground.
2	AGND	P	Analog ground.
20	D+	I/O	USB data plus line.
19	D-	I/O	USB data minus line.
1	Ext-D	P	An External Diode must be connected to this pin for the step-up converter.
24	Ext-I	P	An External Inductance must be connected to this pin for the step-up converter.
18	LED	O	LED indication. This pin is used to indicate the device operation.
14	XTL1	I	Input to the oscillator amplifier and the internal clock generate circuits. To drive the device from the external clock source, XTL1 should be driven, while XTL2 is left unconnected. This pin connects a 4MHz parallel-resonant crystal, or an external source to the on-chip oscillator.
15	XTL2	O	
11	RX	I	Receiver data input.
12	TX	O	Transmitter data output.

17	SEL/ V _{SEN}	I	Interface bus selection, when USB bus mode is selected, this pin must be tied to low before power on. When standard serial bus mode is selected, this pin must be tied to high via external resistor. In the standard serial bus mode, this pin always detect the signal that is sent from the voltage detector, once the system power is failure, the STD200 will execute the deactivate action.
16	T.P	I	Test pin. This pin must be tied to low state when normal operation is doing. For factory use only.
10	CDET	I	Smartcard insert/withdraw detection.
4	CVCC	P	Smartcard power pin.
5	CRST	O	Smartcard reset pin. The voltage is supplied by CVCC.
6	CCLK	O	Smartcard clock pin. The voltage is supplied by CVCC.
8	CIO	I/O	Smartcard I/O pin. The voltage is supplied by CVCC.
7,9	CC4/CC8	O	Smartcard pin C4/C8. The voltage is supplied by CVCC.
13	NC	-	Not connected.

Electrical Characteristics

➤ Absolute Maximum Ratings

Symbol	Ratings	Value	Unit
V _{DD} - V _{SS}	Supply voltage	6.5	V
V _{IN}	Input voltage	V _{SS} - 0.3 to V _{DD} + 0.3	V
V _{OUT}	Output voltage	V _{SS} - 0.3 to V _{DD} + 0.3	V
ESD	ESD susceptibility	2000	V
ESD _{Card}	ESD susceptibility for card pads	4000	V
I _{VDD_i}	Total current into V _{DD_i} (source)	250	mA
I _{VSS_i}	Total current out of V _{SS_i} (sink)	250	mA

➤ Thermal Characteristics

Symbol	Ratings	Value	Unit
R _{thJA}	Package thermal resistance	80	°C/W
T _{Jmax}	Max. junction temperature	V _{SS} - 0.3 to V _{DD} + 0.3	V
T _{STG}	Storage temperature range	V _{SS} - 0.3 to V _{DD} + 0.3	V
P _D	Power dissipation	500	mW

➤ DC Characteristics

GENERAL						
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{DD}	Supply voltage		4.0		5.5	V
f _{OSC}	External clock source			4		MHz
T _A	Ambient temperature range		0		70	°C
I _{DD}	Supply current in RUN mode	f _{OSC} = 4MHz		10	15	mA
	Supply current in WAIT mode	f _{OSC} = 4MHz		3		mA
	Supply current in HALT mode (suspend mode for USB)	External I _{LOAD} = 0mA			500	μA

LED PINS						
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I _{Lsink}	Low current	V _{pad} > V _{CARD-2.4}	2		4	mA
I _{Lsink}	High current	V _{pad} > V _{CARD-2.4}	5.6		8.4	mA

RX/TX PINS						
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
VIL	Input low level voltage	$V_{pad} > V_{CARD}-2.4$			$0.3 \times V_{DD}$	mA
VIH	Input high level voltage	$V_{pad} > V_{CARD}-2.4$	$0.7 \times V_{DD}$			mA
VHYS	Schmidt trigger voltage hysteresis			400		mV
VOL	Output low level voltage for Standard I/O port pins	$I = -5\text{mA}$			1.3	V
		$I = -2\text{mA}$			0.4	
VOH	Output high level voltage	$I = 3\text{mA}$	$V_{DD}-0.8$			V
IL	Input leakage current	$V_{SS} < V_{PIN} < V_{DD}$			1	μA
ISV	Static current consumption	Floating input mode			200	μA
RPU	Pull-up equivalent resistor		50	90	170	K Ω
RPD	Pull-down equivalent resistor		20	40	100	K Ω
toHL	Output high to low level fall time for pins	$C_L = 50\text{pF}$	18		23	ns
tolH	Output L-H rise time for pins		19		28	ns

➤ **SMARTCARD SUPPLY SUPERVISOR ELECTRICAL CHARACTERISTICS**

($T_A = 0 \text{ --} +70^\circ \text{ C}$, $4.0 < V_{DD} - V_{SS} < 5.5\text{V}$ unless otherwise specified)

SUPERVISOR						
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
5V regulator output (for IEC7816-3 Class A Cards)						
V _{CARD}	Smartcard Power Supply Voltage		4.6	5.00	5.4	V
I _{SC}	Smartcard Supply Current		55			mA
I _{OVDET}	Current Overload Detection				120	mA
t _{IDET}	Detection time on Current Overload		170		1400	μs
t _{OFF}	V _{CARD} Turn off Time	$C_{LOAD\text{max}} \leq 4.7\mu\text{F}$			750	μs
t _{ON}	V _{CARD} Turn on Time	$C_{LOAD\text{max}} \leq 4.7\mu\text{F}$		150	500	μs
V _{CARD_OK}	V _{CARD} above minimum supply voltage		4.52		4.76	V
I _{VDD}	V _{DD} supply current				100	mA
3V regulator output (for IEC7816-3 Class B Cards)						
V _{CARD}	Smartcard Power Supply Voltage		2.7		3.3	V
I _{SC}	Smartcard Supply Current		50			mA
I _{OVDET}	Current Overload Detection				100	mA
t _{IDET}	Detection time on Current Overload		170		1400	μs
t _{OFF}	V _{CARD} Turn off Time	$C_{LOAD\text{max}} \leq 4.7\mu\text{F}$			750	μs

tON	V _{CARD} Turn on Time	C _{LOADmax} ≤4.7uF		150	500	μs
V _{CARD_OK}	V _{CARD} above minimum supply voltage		2.50		2.75	V
1.8V regulator output (for IEC7816-3 Class C Cards)						
V _{CARD}	Smartcard Power Supply Voltage		1.65		1.95	V
I _{SC}	Smartcard Supply Current		20			mA
I _{OVDET}	Current Overload Detection				100	mA
t _{IDET}	Detection time on Current Overload		170		1400	μs
t _{OFF}	V _{CARD} Turn off Time	C _{LOADmax} ≤4.7uF			750	μs
t _{ON}	V _{CARD} Turn on Time	C _{LOADmax} ≤4.7uF		150	500	μs
V _{CARD_OK}	V _{CARD} above minimum supply voltage		2.50		2.75	V
I _{VDD}	V _{DD} supply current		1.58		1.68	mA
Smartcard CLKPin						
V _{OL}	Output Low Level Voltage	I=-50uA			0.4	V
V _{OH}	Output High Level Voltage	I=50uA	V _{CARD} -0.5			V
I _L	Input Leakage Current	V _{SS} <V _{IN} <V _{SC_PWR}	-10		-10	μA
T _{OHL}	Output H-L Fall Time	C _I =30pF			20	ns
T _{OLH}	Output L-H Rise Time	C _I =30pF			20	ns
F _{VAR}	Frequency variation				1	%
F _{DUTY}	Duty cycle		45		55	%
P _{OL}	Signal low perturbation		-0.25		0.4	V
P _{OH}	Signal high perturbation		V _{CARD} -0.5		V _{CARD} +0.25	V
I _{SGND}	Short-circuit to Ground				15	mA
Smartcard I/O Pin						
V _{IL}	Input Low Level Voltage				0.5	V
V _{IH}	Input High Level Voltage		0.6V _{CARD}			V
V _{OL}	Output Low Level Voltage	I=-0.5mA			0.4	V
V _{OH -}	Output High Level Voltage	I=20uA	0.8V _{CARD}		V _{CARD}	V
I _L	Input Leakage Current	V _{SS} <V _{IN} <V _{SC_PWR}	-10		10	A
I _{RPU}	Pull-up Equivalent Resistance	V _{IN} =V _{SS}		11	18	KΩ
T _{OHL}	Output H-L Fall Time	C _I =30pF			0.8	us
T _{OLH}	Output L-H Rise Time	C _I =30pF			0.8	us
P _{OL}	Signal low perturbation		-0.25		0.4	V
P _{OH}	Signal high perturbation		0.8V _{CARD}		V _{CARD} +0.25	V
I _{SGND}	Short-circuit to Ground				15	mA
Smartcard RST C4 and C8 Pin						
V _{OL}	Output Low Level Voltage	V _{SS} <V _{IN} <V _{SC_PWR}	-	-	0.4	V
V _{OH}	Output High Level Voltage	I=20uA	V _{CARD} -0.5		V _{CARD}	V
I _L	Input Leakage Current		-10	-	10	μA
T _{OHL}	Output H-L Fall Time	C _I =30pF	-		0.8	us
T _{OLH}	Output L-H Rise Time	C _I =30pF	-		0.8	us

POL	Signal low perturbation		-0.25		0.4	V
POH	Signal high perturbation		0.8V _{CARD}		V _{CARD} +0.25	V
ISGND	Short-circuit to Ground				15	mA

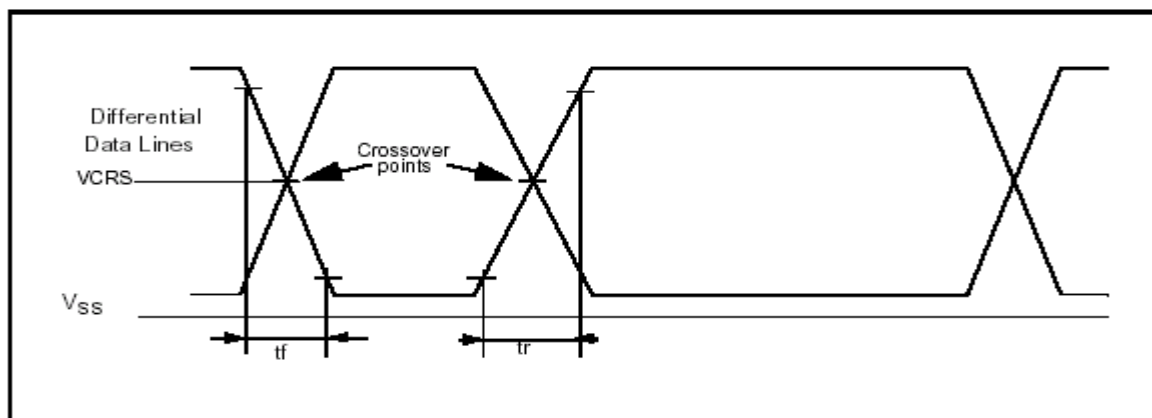
➤ COMMUNICATION INTERFACE CHARACTERISTICS

Symbol	Parameter	Conditions	Min.	Max.	Unit
Input Levels:					
V _{DI}	Differential Input Sensitivity	I (D+, D-)	0.2		V
V _{CM}	Differential common Mode Range	Includes V _{DI} range	0.8	2.5	V
V _{SE}	Single Ended Receiver Threshold		1.3	2.0	V
Output Levels:					
V _{OL}	Static Output Low	R _L of 1.5K ohms to 3.6V		0.3	V
V _{OH}	Static Output High	R _L of 15K ohm to V _{SS}	2.8	3.6	V
USBV _{CC}	USBV _{CC} : voltage level	V _{DD} =5v	3.00	3.60	V

Note 1: R_L is the load connected on the USB drivers.

Note 2: All the voltages are measured from the local ground potential.

Figure.5: USB: Data Signal Rise and Fall Time



USB: Full speed electrical characteristics

Symbol	Parameter	Conditions	Min.	Max.	Unit
Driver characteristics:					
t _r	Rise time	Note 1, C _L =50 pF	4	20	ns
t _f	Fall Tim	Note 1, C _L =50 pF	4	20	ns
t _r f _m	Rise/ Fall Time matching		90	110	%
V _{CRS}	Output signal Crossover Voltage		1.3	2.0	V

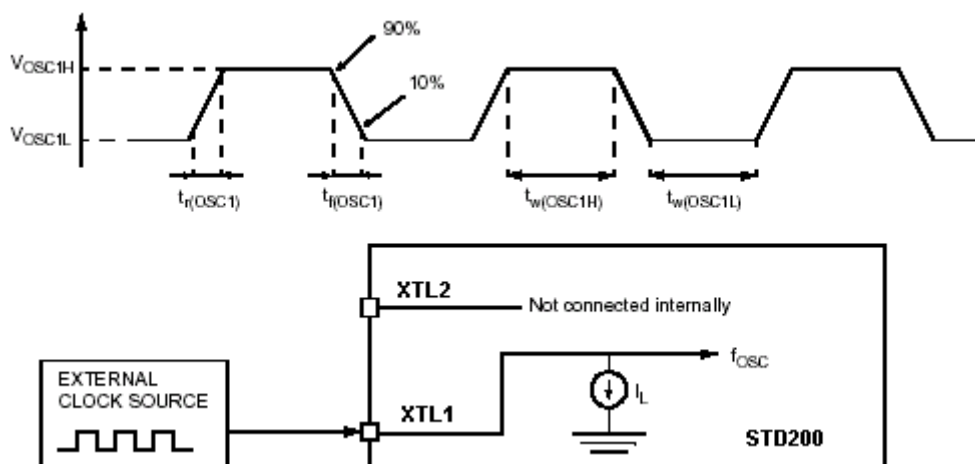
Note1: Measured from 10% to 90% of the data signal. For more detailed information, please refer to Chapter 7 (Electrical) of the USB specification (version 1.1).

➤ CLOCK AND TIMING CHARACTERISTICS

(Operating conditions TA = 0 to +70°C unless otherwise specified)

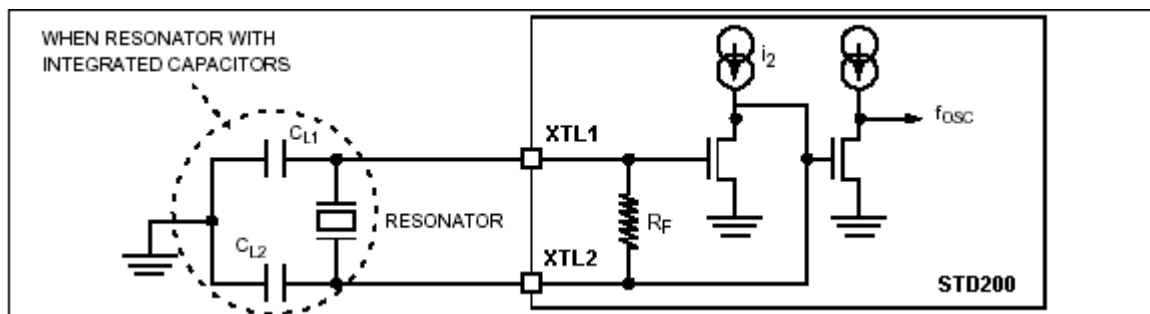
General Timings							
Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
External Clock Source							
V _{OSC1H}	OSC1 input pin high level voltage	See following Figure 6	0.7xV _{DD}		V _{DD}	V	
V _{OSC1L}	OSC1 input pin Low level voltage		V _{SS}		0.3xV _{DD}	V	
t _w (OSC1H) t _w (OSC1L)	see Figure OSC1 high or low time		15		15	ns	
t _r (OSC1) t _f (OSC1)	OSC1 rise or fall time		15		15	ns	
IL	OSCx Input leakage current		V _{SS} ≤ V _{IN} ≤ V _{DD}			±1	μA

Figure 6: Typical Application with an External Clock Source



The ST200 internal clock is supplied with one Crystal resonator oscillator. All the information given in these paragraphs are based on characterization results with specified typical external components. In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and start-up stabilization time. Refer to the crystal resonator manufacturer for more details (frequency, package, accuracy...).

General Timings						
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f _{OSC}	Oscillator Frequency	MP: Medium power oscillator		4		MHz
R _F	Feedback resistor	f=4MHz	20		40	KΩ
C _{L1} C _{L2}	Recommended load capacitances versus equivalent serial resistance of the crystal resonator (R _S)	R _S =200Ω MP oscillator	32		46	pF
i ₂	OSC2 driving current	V _{DD} =5V MP oscillator V _{IN} =V _{SS}	110		190	μA

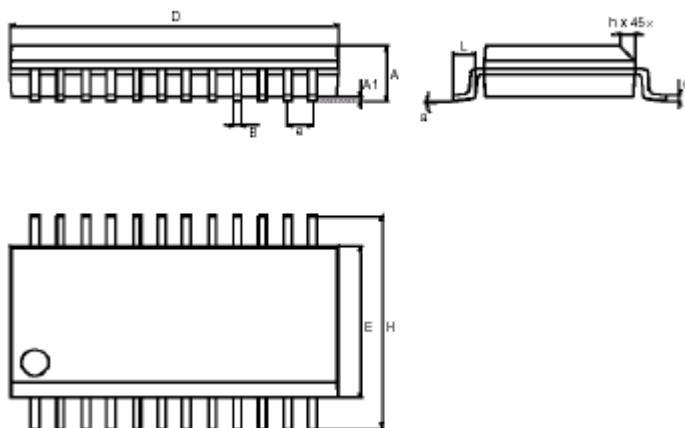


Notes:

1. Resonator characteristics given by the crystal resonator manufacturer.
2. t_{su}(OSC) is the typical oscillator start-up time measured between V_{DD}=2.8V and the fetch of the first instruction (with a quick V_{DD} ramp-up from 0 to 5V (<50 μs)).
3. The oscillator selection can be optimized in terms of supply current using an high quality resonator with small R_S value. Refer to crystal resonator manufacturer for more details.

Package Information:

SO-24 pin



Dim.	mm			inches		
	Min	Typ	Max	Min	Typ	Max
A	2.35		2.65	0.093		0.104
A1	0.10		0.30	0.004		0.012
B	0.33		0.51	0.013		0.020
C	0.23		0.32	0.009		0.013
D	15.20		15.60	0.599		0.614
E	7.40		7.60	0.291		0.299
e		1.27			0.050	
H	10.00		10.65	0.394		0.419
h	0.25		0.75	0.010		0.030
α	0°		8°	0°		8°
L	0.40		1.27	0.016		0.050
Number of Pins						
N	24					
Dim.	mm			inches		
	Min	Typ	Max	Min	Typ	Max